



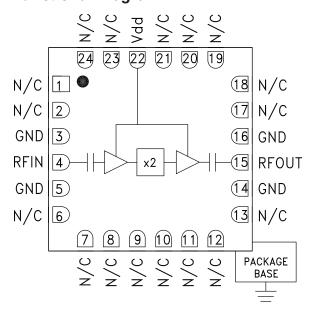
SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 27 - 31 GHz OUTPUT

Typical Applications

The HMC577LC4B is suitable for:

- Clock Generation Applications:
 SONET OC-192 & SDH STM-64
- Point-to-Point & VSAT Radios
- Test Instrumentation
- Military & Space

Functional Diagram



Features

Very High Output Power: +20 dBm Low Input Power Drive: -2 to +6 dBm

Very High Fo, 3Fo Isolation: >55 dBc @ Fout= 29 GHz

100 KHz SSB Phase Noise: -128 dBc/Hz

Single Supply: +5V @ 213 mA

24 Lead 4x4mm QFN Package: 16mm²

General Description

The HMC577LC4B is a x2 active broadband frequency multiplier utilizing GaAs PHEMT technology in a leadless RoHS compliant SMT package. When driven by a +5 dBm signal, the multiplier provides +20 dBm typical output power from 27 to 31 GHz. The Fo and 3Fo isolations are >55 dBc at 29 GHz. The HMC577LC4B is ideal for use in LO multiplier chains for Pt-to-Pt & VSAT Radios yielding reduced parts count vs. traditional approaches. The low additive SSB Phase Noise of -128 dBc/Hz at 100 kHz offset helps maintain good system noise performance. The RoHS packaged HMC577LC4B eliminates the need for wire bonding, and allows the use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vdd = +5V, 5 dBm Drive Level

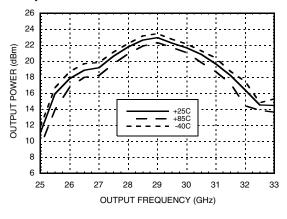
Parameter	Min.	Тур.	Max.	Units
Frequency Range, Input		13.5 - 15.5		
Frequency Range, Output		27 - 31		
Output Power	15	20		dBm
Fo Isolation (with respect to output level)		60		dBc
3Fo Isolation (with respect to output level)		55		dBc
Input Return Loss		20		dB
Output Return Loss		7		dB
SSB Phase Noise (100 kHz Offset)		-128		dBc/Hz
Supply Current (Idd)		213		mA



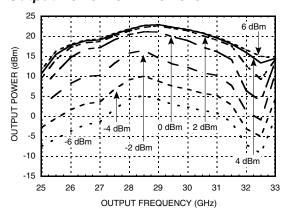


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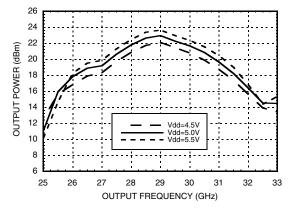
Output Power vs. Temperature @ 5 dBm Drive Level



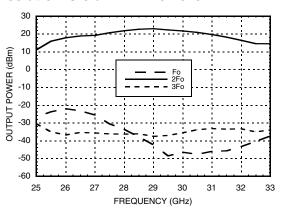
Output Power vs. Drive Level



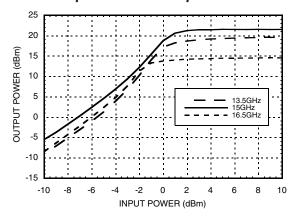
Output Power vs. Supply Voltage @ 5 dBm Drive Level



Isolation @ 5 dBm Drive Level



Output Power vs. Input Power

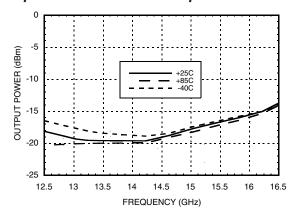




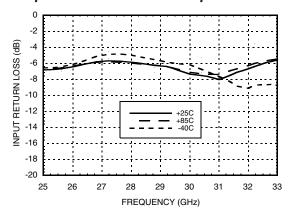


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Input Return Loss vs. Temperature



Output Return Loss vs. Temperature







SMT GaAs MMIC x2 ACTIVE FREQUENCY **MULTIPLIER, 27 - 31 GHz OUTPUT**

Absolute Maximum Ratings

RF Input (Vdd = +5V)	+13 dBm		
Supply Voltage (Vdd)	+6.0 V		
Channel Temperature	175 °C		
Continuous Pdiss (T= 85 °C) (derate 13.8 mW/°C above 85 °C)	1.24 W		
Thermal Resistance (channel to ground paddle)	73 °C/W		
Storage Temperature	-65 to +150 °C		
Operating Temperature	-40 to +85 °C		

Typical Supply Current vs. Vdd

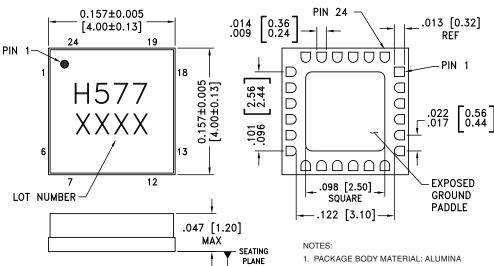
Vdd (Vdc)	Idd (mA)			
4.5	212			
5.0	213			
5.5	214			

Multiplier will operate over full voltage range shown above.



Outline Drawing

BOTTOM VIEW



-C-

- 1. PACKAGE BODY MATERIAL: ALUMINA
- 2. LEAD AND GROUND PADDLE PLATING: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Nun	nber	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC577L	_C4B	Alumina, White	Gold over Nickel	MSL3 [1]	H577 XXXX

^[1] Max peak reflow temperature of 260 °C

^{[2] 4-}Digit lot number XXXX





SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 27 - 31 GHz OUTPUT

Pin Description

Pin Number	Function	Description	Interface Schematic		
1, 2, 6 - 13, 17 - 21, 23, 24	N/C	These pins are internally not connected; however, this product was specified with these pins connected to RF/DC ground.			
3, 5, 14, 16	GND	Package bottom must also be connected to RF/DC ground.	GND =		
4	RFIN	Pin is AC coupled and matched to 50 Ohms.	RFIN ○── ├──		
15	RFOUT	Pin is AC coupled and matched to 50 Ohms.	— —⊙ RFOUT		
22	Vdd	Supply voltage 5V ± 0.5V. External bypass capacitors of 100 pF, 1,000 pF and 2.2 μF are required.	Vdd =		

Application Circuit

				_				
Component	Value) J3			
C1	100 pF							
C2	1,000 pF				C1 =	± C2	<u>_</u>	C3 🖶
С3	2.2 μF				_			
					-	-	=	=
					22			
				V	dd			
				•	uu			
		4						
	<u> </u>	4	RFIN		П	COLIT	15	
	J1		KLIIN		П	POUT		J2
	31		l H	MC57	7LC4	ŀВ		JZ
				0.1				
				Gr	۷D			
					3.5.	14,16		
					-,-,	,		
				=	_			